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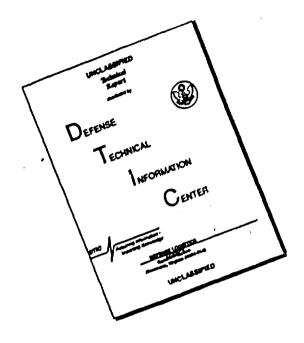
SCIENTIFIC AND TECHNICAL INFORMATION

CAMERON STATION, ALEXANDRIA, VIRGINIA



UNCLASSIFIED

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ELECTRONICS MATERIEL AGENCY

### GENERAL ELECTRIC



ELECTRONICS MATERIEL AGENCY

U. S. ARMY

PRODUCTION ENGINEERING MEASURE

DA - 36 - 039 - SC - 86727

SILICON PLANAR EPITAXIAL TRANSISTOR

TYPE 2N2193

FOURTH QUARTERLY REPORT

31 JANUARY 1963 30 APRIL 1963

PROJECT MANAGER

#### TABLE OF CONTENTS

	P	P	<u> </u>
AREA OF WORK - IMPROVED KPR RESOLUTION (Completed)	1		
AREA OF WORK - CONTACT EVAPORATION AND ALLOYING Work Item - Improved Substrate Heater Design Abstract Purpose Narrative and Data Conclusions	1	1	
Program for next Quarter (Completed) Work Item - Temperature Control Improvements (Completed) Work Item - Regulated Leak Consideration (Pre-empted) Work Item - Vacuum Deposition Process Abstract Purpose		2 2 2	
Narrative and Data Conclusions Program for next Quarter (Completed)			
AREA OF WORK - COLLECTOR ETCHING (Completed)	3		
AREA OF WORK - BORON DIFFUSION (Completed)	3		
AREA OF WORK - PHOSFHORUS DIFFUSION (Completed)	3		
AREA OF WORK - COLLECTOR CONTACT TO THE HEADER  Work Item - Reduction in Size of Preform  Abstract Purpose Narrative and Data Conclusions (Completed)  Work Item - Reduction of the Corroding Species by Improving Cleaning	3	3	i
and Tighter Inspection of Purchased Material Abstract Purpose Narrative and Data Conclusions Program for next Quarter (Completed)		4	
AREA OF WORK - INTERCONNECTIONS  Work Item - Improve Bonding Process Abstract Purpose Narrative and Data Conclusions (Completed)	5	5	1
AREA OF WORK - RELIABILITY MEASUREMENT  Work Item - Completion of Phase II Pre-Test Experiments, Including the addition and Completion of Several Other Pre-Tests not Previously Mentioned. Completion of Voltage plus Temperature Stress on the Phase II Screen Experiment	7	7	

TABLE C	F CON	ITENTS (	Cont.)
---------	-------	----------	--------

	<u>P</u>	<u>P</u>	<u>P</u>
Abstract			7
Purpose			7
Narrative and Data			9 36 36
Conclusions			36
Program for next Quarter			36
ADDA OF MADE THE THE THE TOTAL AND AUTO TOTAL ACCUMENTS A TANK	غ ز		
AREA OF WORK - INSPECTION AND QUALITY CONTROL PLAN	50		
Work Item - Inspection and Quality Control Manual	٥٥	36	
	30	36	36
Work Item - Inspection and Quality Control Manual	30	36	36 37 37

- I. AREA OF WORK IMPROVED KPR RESOLUTION (C. LOGAN)
- 1 A. Work Item Improved light collimation during KPR exposure.

This work item has been completed.

2 A. Work Item - Mask Wafer "Contact" Exposure Effects.

This work item has been completed.

3 A. Work Item - High Resolution basks.

This work item has been completed.

- II. AREA OF WORK CONTACT EVAPORATION AND ALLOYIN; (C. LOGAN)
- 1 A. Work Item Improved Substrate Heater Design.
  - B. Abstract Improved substrate heaters of the lesion described in the previous raports have been installed and are being used for vapor eposition processing. A number of analytical techniques were assessed for contact evaluation relative to process monitoring.
  - Consistent and uniform aluminum contact surfaces and alloy necessitates controlled deposition and alloy temperatures. The improved heater design has been developed to minimize temperature are ient effects which are characteristic of lar e area electrical resistance neuters.
  - D. Narrative -- Work during this quarter has consisted of the evaluation of a and Data number of analytical techniques for defining the quality of the contact process. The following techniques were evaluated:
    - 1. Cross-sectioning,
    - 2. Ultrasonic Vibration,
    - 3. Flysical Abrasion.
    - 4. Dissolution of the contact metal followed by microscopic examination of the substrate.

A cross-sectioning technique was developed for measuring the legree of aluminum-silicon interaction, which involved angle-lapping of the transistor structure followed by high magnification microscopic viewing. Due to preferential abrasion of the aluminum which occurred under certain lapping conditions, the reproducibility of this technique was open to question. The feedback time for results was also too long for convenient use, so this technique was abandoned.

The regular clean-up which follows alloying has been expanded to include a high-energy ultrasonic vibration in a water medium. Wafers with marginal alloy quality are immediately recognizable, he to either partial or complete loss of the contacts. Wafers showing small isolated areas of lost aluminum are physically abraded with a sharp pointed instrument to distinguish between everall poor alloy due to some surface condition such as residual oxide or KPR.

A technique for the removal of the aluminum from the contact area using a chemical etch, either HF or HCl, and then viewing the aluminum-silicon interface at high magnification under dark field illumination has been established. This has proven to be a very desirable technique for determining contact alloy quality based on characteristically identifiable interface conditions such as dendrite or pit size and density, silicon regrowth formation and amorphous silicon deposits.

Backing up these analytical procedures is a pre-sampling plan, in which a small number of pellets is fabricated into devices and bondability (ease of thermocompression bonding), strength of the bond (drop test) and electrical resistance of the contact are assessed to establish contact quality.

With the exception of the first technique (cross-sectioning), all these procedures have been a ofted to some degree and are being used for process monitoring.

- E. Conclusions The new infrared heater design has effected a significant improvement in the reproducibility and uniformity of the contact process. These improvements were verified and are being maintained, using the process monitoring techniques described above.
- F. Program This work item has been completed.

  for next

  what ber
- 2 A. Work Item Temperature Control Improvements.

This work item has been completed.

3 A. Work Item - Regulated Leak Consideration.

This work has been pre-empted by the vacuum deposition process (See L A.)

- 4 A. Work Item Vacuum Deposition Frocess.
  - B. Abstract The elevated substrate temperature deposition process has become standard procedure for contact processing.
  - 3. Furpose To develop constant process which would minimize the critical prince of TJ3, Fiermo Compression Bonding, and promote reproducibility of alloy regions having negligible effect on the electrical parameters.
  - D. Narrative Refer to "Marrative and Data" for "Work Item Improved Substrate Heater Design", in "Area of Work Contact Evaporation and Alloying", II 1 D.
  - E. donelysions The playable, temperature depositions, along with the improved
    substitute heater design, have resulted in improved reproducibility
    and uniformit, of the contact process, and hence improved lead
    attachment. Process monitoring techniques, as discussed in II 1 D
    have verifie. Discard will be use to ensure process control.

- F. Program This work item has been completed. for next Quarter
- III. AREA OF WORK COLLECTOR ETCHING (C. LOGAN)
- 1 A. Work Item Surface Masking.

This work item has been completed.

- IV. AREA OF WORK BORON DIFFUSION (A. R. DI FIERRO)
- 1 A. Work Item Replace Present B<sub>2</sub>O<sub>3</sub> Solid Source Process by a BCl<sub>3</sub> Gaseous Source Process.

This work item was terminated, as reported in Quarterly Report No. 3.

- V. AREA OF WORK IHOSPHORUS DIFFUSION (J. F. WHOLEY)
- 1 A. Work Item Improved Source Heater for Phosphorus Diffusion.

This work item has been completed.

2 A. Work Item - Improved Technique of Loading Phosphorus Source Boats.

This work item has been completed.

- VI. AREA OF WORK COLLECTOR CONTACT TO THE READER (R.H. LANZL, J.L. DURSO, J. RICHARDSON)
- 1 A. Work Item Reduction in Size of Preform.

The basic work it has is the debug ing of the preform mount equipment to provide rapid, accurate and reproducible attachment of preforms to headers prior to pellet mount and to optimize further the entire pellet mount process.

- B. Abstract Work progressed to the point where preforms were being applied a contrately at plannel rates. The preform addine was then incorporated in the production line. The addine has subsequently experienced considerable doubtime, the to maintenance problems, but work on this "first energient" machine is considered satisticated and complete.
- d. Furgose The food during this period was to complete the deluging of the prefer mounting equipment.

- D. Narrative and Data Debugging work was completed. More accurate preform ribbon tooling was provided. In order to increase preform placement accuracy still further, a retractable hold-down was incorporated, to control the preform from the time of cutoff until welding took place.
- E. Conclusions The fessibility of this work item was substantiated. Continuing effort must be made to maintain placement accuracy and to minimize equipment downtime, but the basic work item is considered to be complete.
- 2 A. Work Item Reduction of the Corroding Species by Improving Cleaning and Tighter Inspection of Purchased Material (F.K. GLASBRENNER, R.J. KOBLER).
  - B. Abstract During this period line experiments were conducted to determine the effect of thermal cycling on gold adhesion and samples obtained for comparison of "as received" versus "cleaned" parts and placed on high temperature storage tests (300°C. to 350°C. range).
  - C. Furpose To determine if the inspection procedures and tests are adequate in controlling the quality of the gold plate, and to determine the effect of uncleaned headers on device performance.
  - D. Narrative Hitherto, work has been essentially concerned with determining how well the cap, preferm and header meet the drawings, and the effectiveness of the incoming inspection and cleaning processes.

    Recognizing that the header and its finish play the major role in obtaining good alloying or adhesion of pellet to header, devices were fabricated with uncleaned headers, in an attempt to evaluate the effect on the collector contact.

The experiment with cleaned versus uncleaned headers was designed to determine if header cleanliness can contribute to a major mode of failure. After 1,000 hours of baking at both 300°C. and 350°C. on "as received" and "cleaned" parts, the results indicated that there were no opens of pellet to header contact in either group.

1. Cap and Freform.

No additional information was obtained in this area and no changes were made in the drawing, as processing is considered to be necessary at this time, to improve the quality of the product.

#### 2. Header.

To date we have investigated the thickness of gold plate, the identification of base material and the effectiveness of the cleaning process, as determined by infrared analysis. Vendors have been approached on the subject of the purity of their gold plating, but they were unwilling to specify anything more specific than 24 K gold. The purity of the gold used is important, and control of contamination in the gold seems to be a constant problem in the plating processes.

It has been observed during experimentation that subtle variations

between plated parts could affect some line processing operations such as thermocompression bending and could lead to rejections at this work station. These variations have not been detectable by incoming inspection procedures. Therefore, more inspection has been instituted, based on line usage processing, to ensure that poorly plated lots do not reach the production lines.

- E. Conclusions It appears that the level of contamination present in the devices sions is low enough in magnitude to rule it out as a contributor to a major mode of device failure of collector contact, i.e., no opens in "cleaned" or control versus "uncleaned" neader experiment. Therefore, no major changes in header drawings will be initiated.
- F. Program This work item has been completed.
  for next
  Quarter
- VII. AREA OF WORK INTERCONNECTIONS.
- 1 A. Work Item Improve Bonding Process (LANZL, DURSO, KOBLER).
  - B. Abstract 1. Durin this period tests were completed on units fabricated with wate from Vendor B. Recalts of a study of wire specifications and surface each and tion were also completed.
    - 2. Man forwring (divide i mintic.) and been converted to a new walle lesion which previously a little improved bond strength.
  - U. Furpose 1. To determine the effect of naterill from Vendor B on device strong that on the strong of them wire specifications.
    - 2. To obtain an extimum tending process, using a new wedge design.
  - D. Narrative 1:. Serond Sorre of Wire Supply (Vendor B). and Dat

Units f brid ted with wile obtained from Vendor B have been subjected to series of mechanical tests, and the results are as follows:

<u>r. e i</u>

Vendor	Eio	a tion	Trade: of Opens After						
Sangle	Per	Pox	Jentrifuge	3:.0 :k	Cantr.	ıru e	Vi	bration	
3i e	i.E	Vendor					Fatig.	Var. Freq.	
	76	.6	zk KG	1.5 KG	35 KG			20G	
<b>4</b> 0 <b>3</b> 8 38 37	1.5 5.9 13.1 17.1	1 9 13 <b>1</b> 0	2 0 0 1	3 0 0	4105	6329	6 3 2/37 9	6/39 3/37 2/37 9	

Our results inducted that failure rates for the 1% and 16% clongs tion wires were migner than those for the 5% and 13% elongs tion wires.

An order was therefore placed with Vendor B for 500 feet of wire to his 5% - 13% clong tion value range (G.E. measured these elongations is 10% - 11%). When the material was received and tested for compliance with specific tion, it was found to be in the 15% - 16% range, and was returned for replacement. The vendor felt that 10% - 11% was too tight a range to produce consistently, and a compromise range of 5% - 15% was a read upon.

In term, I to this range has been received and is being processed on the production line at the present time. Perform noe will be reported at a later made.

#### 1b. Study of Wire Specific tions

During this period an investibation was completed on the effect of re-nnealing, annealed wire on the clongs tion range and break load of wire from Vendor A. The results re as follows:

Figure 2

Elon	o, tion %	dra king	Local (Gins.)
As Received	After Annealing	As Received	After Annelling
10.1 - 15.4	E.9 - 1.	24.2 - 2 -7	19.5 - 25.0

Therefore, since our resulte tend to hade to only slight change in more nimely properties after re-coulding one wire on small spools and re-nnaling, the clangation range of 9% - 15% appears to be a rescale wire specific tion.

lc. Suri ce Cont min tion of Wire.

Wire from Vender A, "as received", who allecked for organic anterial by influenced an lysis and was found to have 23 \$ 10 ppm, which reduced to 8 \$ 3 ppm ofter the clearing openation. However, samples of a begind from Vender B, which is estimated to have approximately the same "to received" ppm of organic material, were run on 300°C, storage for 1,000 hours with no resulting opens or failures. This may induce to the take difference in scattain tion levels was not significent enough to have any effect on device performance.

ld. The original objective of cotaining more uniform physical proporties of wire has been realized by cotaining two vendors capable of producing material per tab revised specifications. So not reliable of the length for elongation and specification of rate of pull will ensure that this uniformity is maintained.

Therefore, work in this area is complete.

2. Results from wedge design experiments during the last quarter showed that a significant improvement in bond strength could be obtained by changing the wedge design. The device manufacturing line was converted to one of the new designs which has a 4-mil instead of a 2-mil bonding width. This new wedge

- eliminates the second bond to the pellet and results in a considerable approvement in the bonding rate.
- 2b. The bonding process has been modified to recommodate the new wedge design and the first 1,500 (approx.) units fabricated have been used in the electrical screening experiments. The development of this process is considered to be complete, and a manufacturing process has been demonstrated which resulted in significant improvement in conding strength.
- E. Conclusions

  Vendor A in the along tion range of % 15%. This elongation range is seen to be that at which fewest failures are produced and which is nest workable from a manufacturing standpoint.

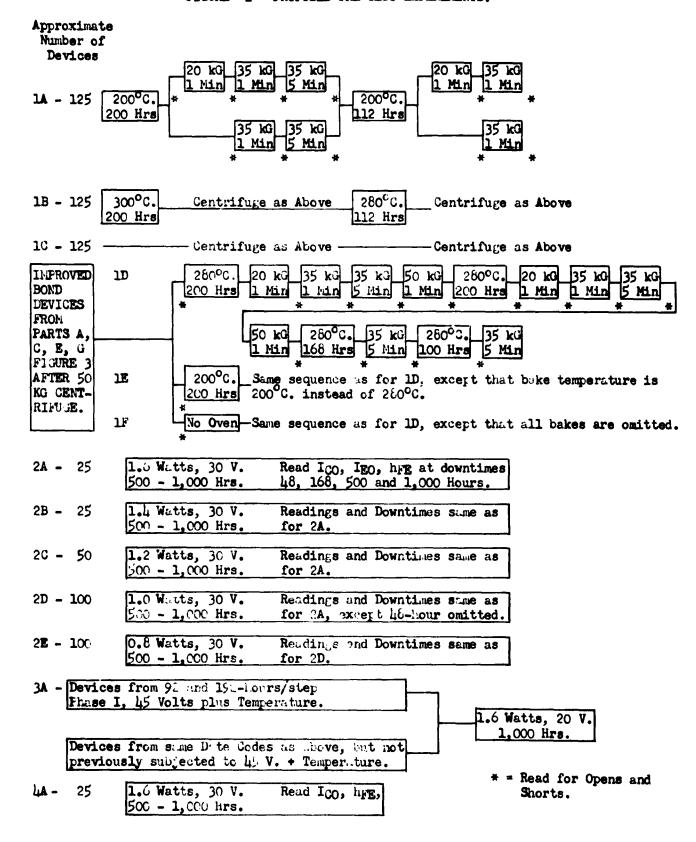
  Surface cont minition on "as received" material was not significantly different from that of "claimed" material in its effect on device performance. Work in this area is complete.
  - 2. The manufacturing line has been converted to a new bonding process which includes an improved wedge design. Work in this area is complete.

#### VIII. AREA OF WORK - RELIABILITY MEASUREMENT ( . E. JACOBS, A. FOX)

- 1 A. Work Item Completion of F. so II FewFest Experiments, Including the Addition of Completion of Sever 1 Other Fro-Fests not Freviously Lentioned.

  Completion of Volt ge plus Temperature Stress on the Phase II Screen Experiment.
  - B. Abstract Figure 1 shows all of had I are II pre-test experiments, including those added since the third quirterly report was issued. Results are shown in Figures 2 through 10. Figure 11 shows the Phase II experiments. Figures 12 through 15 show the analysis of results to date.
  - C. Purpose 1. The pre-tests lister lA through lF in Figure 1 were designed to
    - inside to whether a 100°C, or 1 250°C, pake, ranging in time from 200 hours to 500 hours, would affect the mechanical strength of the gold wire-to-pellet cond. This would indicate how long a voltage plus temperature screen could be run before it affected mechanical strength.
    - b. letermine thether the initial subjection of the devices to 20 KG centrifule would like their subsequent performance at a higher stress.
    - 2. The pre-tosts listed 2A through 2E were run to
      - rotes prevailing nuring the latter melf of 1902. This, in turn, would enable us to take an efficient selection of sample sizes, operating life tests and proportionment of samples between tests.

#### FIGURE 1 - PROPOSED PRE-TEST EXPERIMENTS.



- 3. The pre-test listed 3A was to
  - a. determine whether those devices which had previously showed stability on an extended voltage plus temperature screen (stable Phase I devices from Temperature plus Voltage Step Stress 92 hour and 192 hour treads) were significantly more stable when placed on 1.6 watts, 1,000 hour life than those devices from the same lots which had not previously been subjected to 45 Volts plus temperature.
- 4. LA shows a 3 minute ON, 3 minute OFF cycled 1.6 watt operating life test. The purpose of this test was to determine whether power cycling produced a significantly larger percentage of legitimate failures than non-cycling (The 3 minutes ON time allowed the junction temperature, T<sub>J</sub>, to arrive within 90% 95% of its 1.6 watt steady state temperature).

In general, these pre-tests were performed in order to provide more information than had been obtained during Phase I, because of the high reliability of the product.

D. Narrative - 1. Pre-Tests to Determine the Effect of Temperature on Mechanical and Data Strength (Tests 1A through 1F).

Figure 2 shows the results on standard production line devices, manufactured during the second and third quarters of 1962, which were taken through experiments LA through 1C. Only opens and shorts are classified as failures. From this data there is no reason to suspect that those devices which were previously subjected to a 20 KG stress experience significantly heavier failure rates at the 35 KG level than those devices which were not subjected to the prior 20 KG stress. Although some cases give contrary indication (5 failures in lot 304208, which included 20 KG centrifuge, against 10 failures in lot 305111, which did not include 20 KG centrifuge), the overall results - 20 KG lots versus non-20 KG lots - indicate no significant difference. The data following the second temperature stress also supports this argument: no further failures.

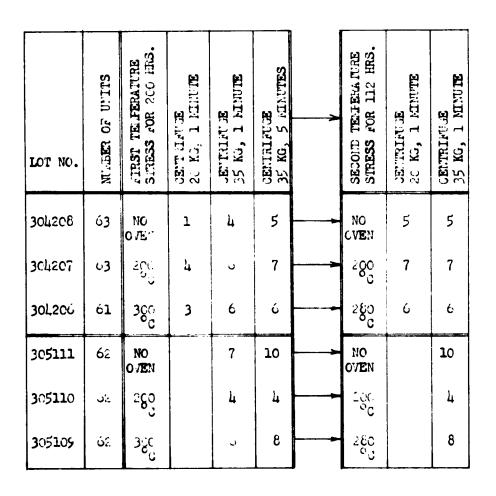
The d.t. also indicates that those devices which received oven stress for 312 hours, either at 200°C, or at 280°C, are apparently act significantly weaker mechanically than those devices which did not receive oven stress.

5. tistic 1 results supporting the two no-significance contentions state above are as follows:

FIGURE 2

PHASE II PRE-TEST EXPERIMENTS

EFFECT OF OVEN STORAGE ON MECHANICAL STRENGTH



TWO BY TWO CONTINGENCY TABLE FOR A CHI SQUARE TEST ON THE EFFECT OF 20 KG PRE-CENTRIFUGE ON 35 KG MECHANICAL STRENGTH.

	DEVICES FRIOR EXIERI  OUSSERVED	20 KG	DEVICE PRIOR EXPERI C. SERVED	MARGINAL TOTALS	
CUMULATIVE NUMBER OF DEVICES FAILING BY (AND INCLUDING) FOR 35 KG,	22	20	16	20	40
CUMULATIVE NUMBER OF DEVICES FASSIN FEY (AND I CLUDING) THE 35 kJ, AMUTE LEVEL	<b>1</b> c4	156	105	157	333
NARGINAL FOINIS	100		16,		373

T. 1. 
$$X = \frac{\left\{ \left| \frac{1}{1} \right|^{1} \left| \frac{1}{2} \right| - \frac{f_{12}(1)}{1} \right| - \left( \frac{N}{2} \right) \right\}^{2} y}{(f_{12} + f_{11})(f_{21} + f_{21})(f_{11} + f_{12})(f_{11} + f_{12})} = 0.068$$

If some relative of the control of the standard with the control of the solution of the solut

31 dl rly for two of the collamper wro pre-stress conditioning for 300 hours on 33 KF, eccladed strong Mar.

	OVEH FRI	e-stress	C. OVEN I Sika	Fre— Ejs	DEVICES V C. CVEN I SIN	narginal Totals	
	OBSERVED	EXTEN UED	O.SE(VE)	exisc let	CBSERVED	EXPECTE:	
JU ULATIVA JAILURUS AT THE JOULEVEL	ž	13.4	11	13.4	14	13.2	710
CULUIATIVE MON- MILURES AS THE 35 KJ LEVEL	110	111.	114	111.0	105	1.9.8	333
IA CANAL TOTALS	ۇ يا		125		123		373

$$\sum (x^2)_{Actual} = 1.111$$

Oni square tobles show that if the processes are identical there is 6.55% probability that the above differences would be observed. In this case,  $\chi^2_{-\infty} = 4.01$  for two degrees of freedom. This information shows again that there

is no reason to believe that oven stressing for 300 hours will influence the performance of the devices at 35 KG.\*

Experiments 1D, 1E and 1F are similar to the experiments just described except that the devices used were fabricated with improved wire and using improved bonding techniques, as described in the first column of Figure 3, the results table. The conclusions derived here do not conflict with those shown in Figure 2. Because of the improved bonding techniques, however, the failure rates are either small or non-existent. Note that a total of over 600 hours has been accumulated on these improved devices, with only the double-bonded, type "C" wire, devices showing the effect of the oven hours.

2. Pre-tests to Determine the Performance of the Froduct on Operating Life Stresses Above the Normal Fower Rating for the Device.

Figures 4, 5, 6, 7 and 8 show scattergrams of  $I_{CO}$  at 60 V. and here (via an  $I_{B}$  presentation:  $I_{C} = 1$  mA.) stability over 1,000 hours of 1.6 W., 1.4 W., 1.2 W., 1.0 W. and 0.8 Watts respectively. (here at 1 V.; 150 mA. was taken, but the zero-hour readings were found to be invalid).

Comparison of these figures indicates that no significant difference exists in the ICO and her shifts observed for the various stresses. The difference in percent failure between stresses is not significant either, no matter how the failure end-point is selected.

3. Pre-Tests to Determine the Effect of 1.6 Watt, 1,000-hour, Operating Life on Devices Which have Shown Stability on a Prior Long-Term Voltage Plus Temperature Fest (Devices from Phase I, 45 V. + Temperature Step-Stress, 92 and 192-hour treads, versus Controls of 20 V. + Power, 1 and 4-hour treads).

See Figure 5. The 1,000-hour scattergram of I<sub>CO</sub> shows no significant difference in failure rates between the 45 V. + Temperature devices and the "controls". Since reject analysis has not yet been performed on the devices, we cannot establish inversion layer troubles as the cause of failure. Regardless of the problem, however, the comparison is discouraging, since it would indicate that a voltage plus temperature screen might not be effective in reducing the major cause of failure.

Although the influre rates observed for this test may be conquired to one another, they should not be compared to failure rates existing in the pre-tests previously described, unless the fact that these devices were obtained earlier is taken into account.

h. Pre-Tests to Determine the Effect of Cycling on Reliability.

These devices (Figure 10) and the devices presented in Figure 4 were obtained from the same production lots. Although three minutes of ON cycle will allow the case and the junction of the device to reach 90% - 90% of its steady-state 1.6 Watt value - so that junction temperatures of the cycled devices are close to those of

<sup>\* =</sup> Note that this information is not in conflict with information given in the third quarterly rejert, which states that temperature aging for short periods of time (72 hours) appeared to improve the mechanical strength of the device.

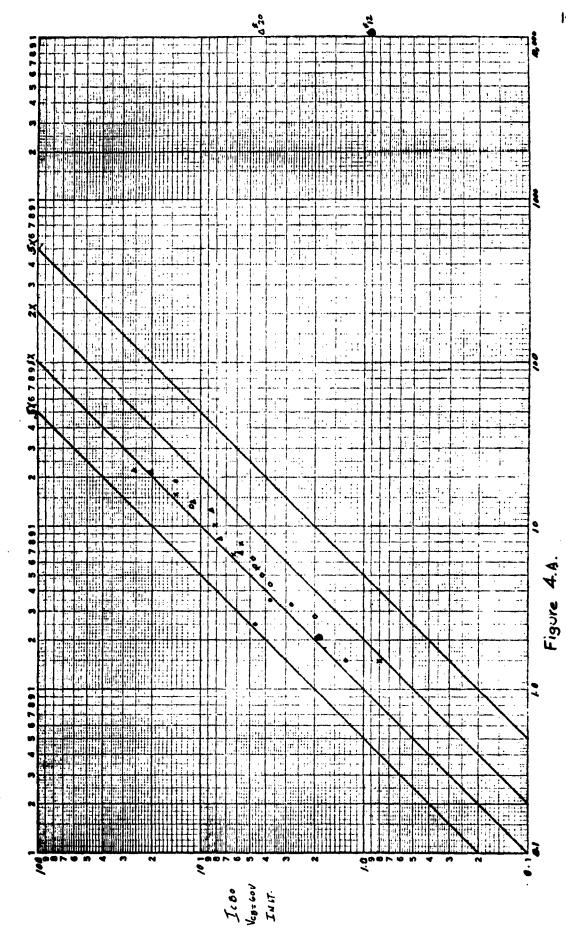
FILURE 3 - PHASE II PRE-TEST EXFERENCES

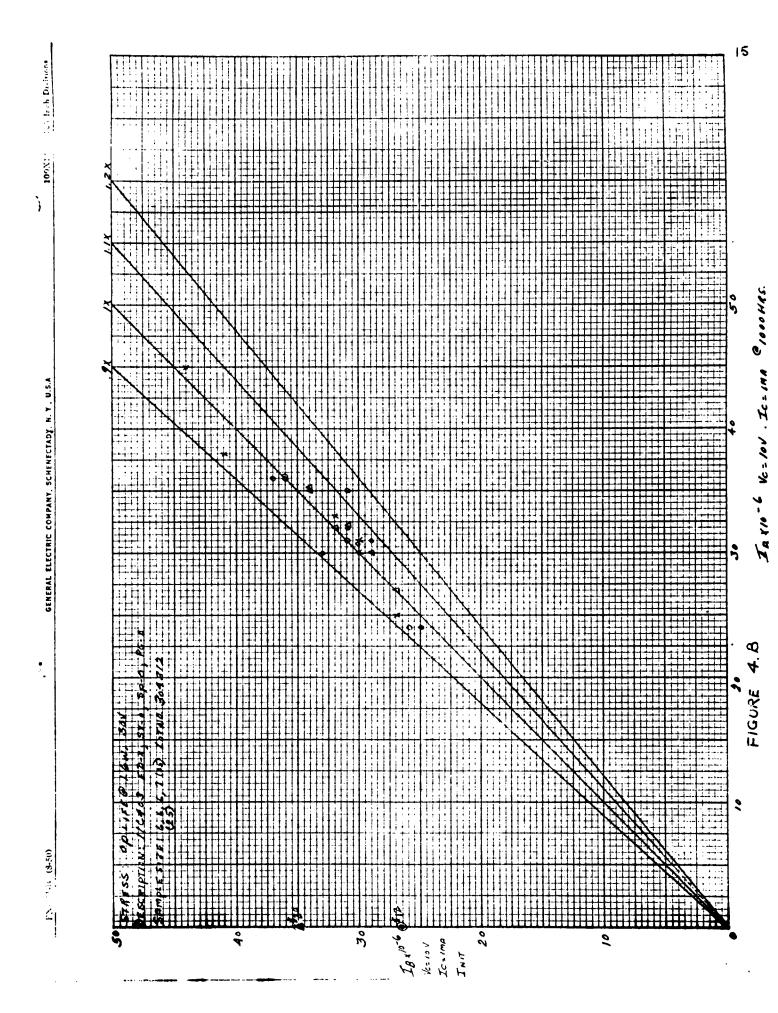
STRENGTH
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STORAE
<b>河</b>
Ŏ
TOBEFE

								13
32 kg² 2 win°	000	H0%	000	000				
TRNFERATURE PROTECTION TOOL STIN OOL ROSI	NO OVEN 2000C 250°C	NO OVEN 200°C 280°C	HIC OVEN 200°C 1280°C	NO CVEN 200°C 280°C				
32 KG' 2 WIN'	000	404	000	000				•
TEITERATURE THIRD STRESS FOR 165 HRS.	-NO OVEN - 200°C - 250°C	NO OVEN ≥2000 = 260°C	NC OVEN 200°C 280°C	NO OVEN _CCO 260°C				
SO KG' T VIIN'	000	-100	000	000				
32 KG 2 FIN	000	r400	000	000				
38 KG'T MUN'	000	400	000	000				
SO KIP I PIN	000	400	W 5 Q	၁၁၀				
TELT EKATURE SECOND STRESS FOR LOCHES.	10 6√81 206°0 266°0	1C 07E:: 200°C 260°C	NG GVENT 5つつうこ 20つつうこ	NO OVEN 200°C 260°C				
°NIN T का 05	000	400	2000	220	·····			
32 KG 2 NUN.	000	) O O	000	ပဝဝ				
32 KG I UTM	000	000	0 G	၁၀၀				
SO KA, I MA.	၁၁	<b>∵00</b>	000	000				
TEMFEMATINESS FOR SCO HRS.	NC OVEN 200°C 260°C	NO CVEN 200°C 200°C	NC OVEN ≥00°0 ≥60°0	NO OVEN 2009C 280°C				
SITNO FO OL	3 & G	7	<b>3</b> ⊱ Ω	20-6				
TO KG T TIN	7	10	.4	67	<u> </u>	25	17	50
35 KL, LILIN.	Н	1	0	1	~	91	٣	13
KO. C. UPTES	ેટ	3c	25.	25	1.7	28	77	23
SCURCE MATERIAL LOT # 253	SANJU AND ANED A WIDE WINGE ONE BOYD ON IYEE HOW WIRE	CAKED AND ABED CONTAINED TWO ECTES ON TYPE "U" WIRE	EAKED AND AGED  WIDE VEDJE - OUE BOND SIANDARD WIRE	BAKED AND AGED SFALL WEDGE - INC BOIDS STAILDARD WIRE	ng bake, abed Mide Wedge - One bond On ithe "C" wire	NG EAKE, AGED D SYAIL WENGE - INO BOYDS ON TYPE "C" WIRE	NO BAKE, ACED F WIDE WEDGE - ONE BOND STANDARD WIRE	NO BAKE, A JED SYALL WEDGE - INO BOYDS STANDAR WINE

MOSARITHMIC 399-125G

STACS OP.11FE @ 1.6 W, 30 V
DESCRIPTION //C403 ED-x; 51-0; 89-0, PG-4
SANPLE SIZE: 4, 6, 1, 1 LOTNO. 304312





ماا

Miles Professional 359-125G

DEECKIPTION 116403 ED-X; SX-0; SP-0, PG-A SAMPLE SIZE : 44 (12,13,12,12) LOTNO. 364314 STRESS: 09.11FE @ 1.4W, 30V

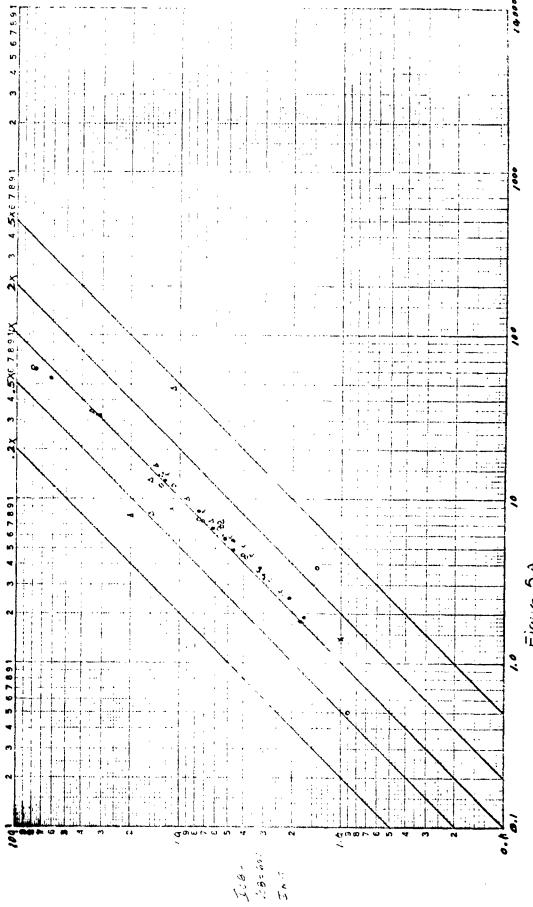


Figure 5 A.

ICBO CVCB=60V, 1000 HAS.

100X140 7/100 let la

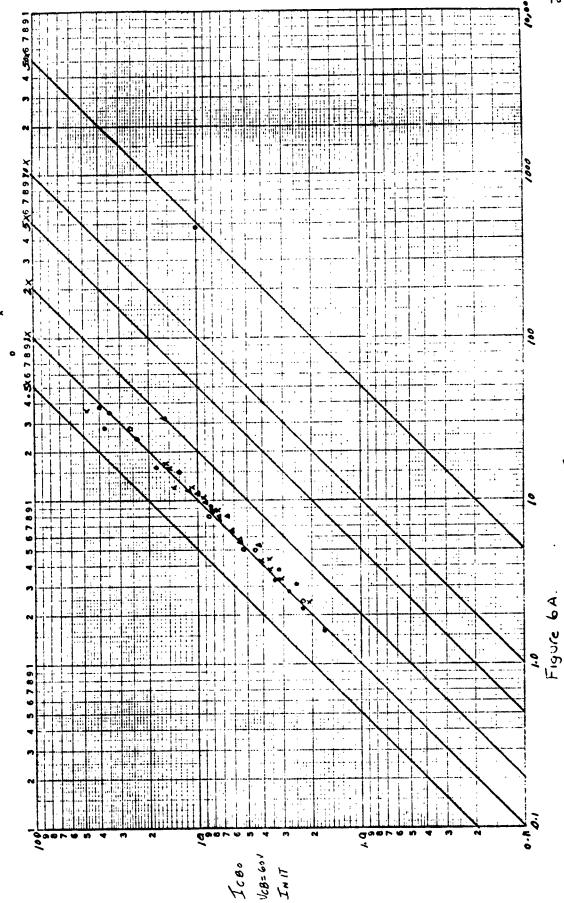
GENERAL ELECTRIC COMPANY, SCHENECTADY, N. Y., U.S.A

FN-521-B (8-50)

ICBO VCB- 634 1000H13.

FACT TOURTHMIC SEC 125G FACT TO A SEC 125G SEC 125G

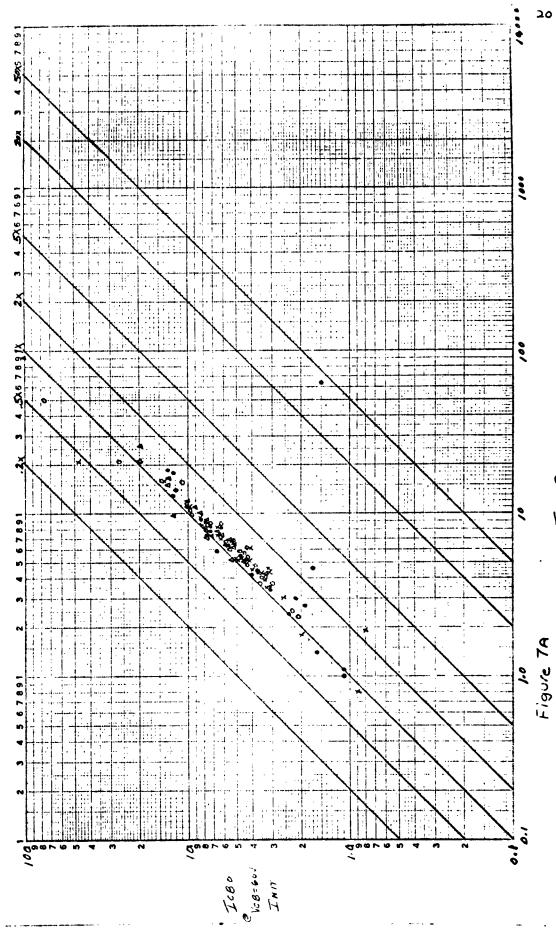
STARESS OF LIFE PIZM, 301 DESCRIPTING 15403 ED-X, Sx. 0, 50-0, DG-4 SAMPLESIZF SO, 13,12,13,13, LOTNO 304313



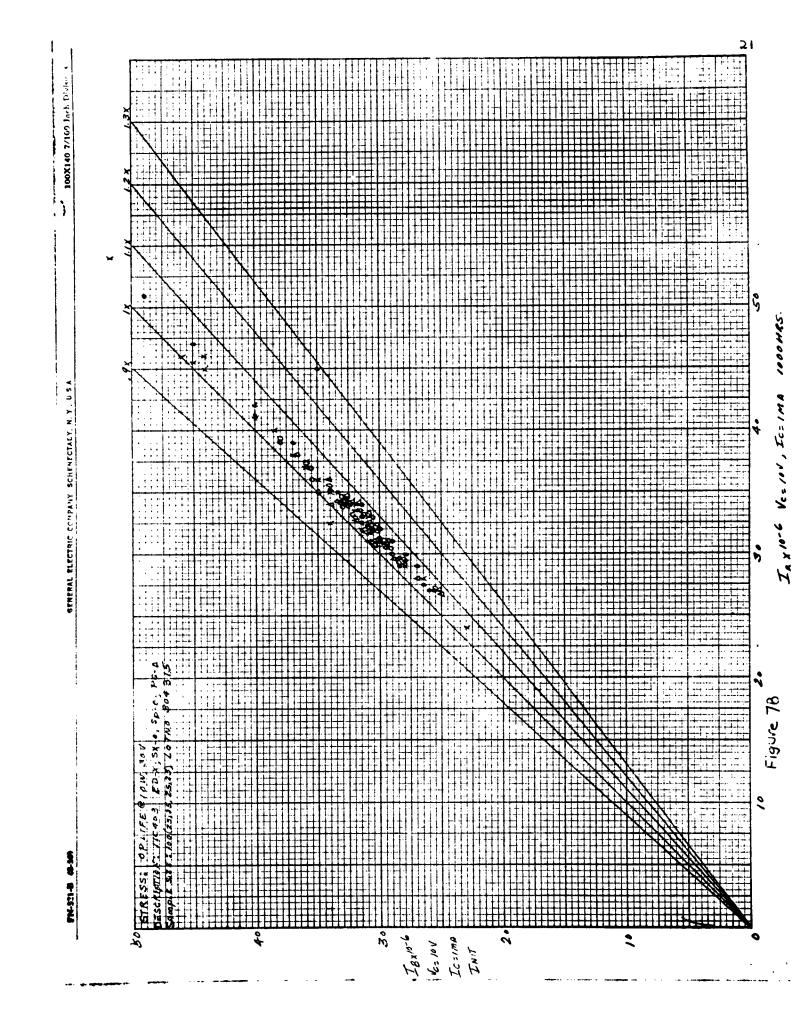
IB YIO-6 VC=10V, IC=IMA @ 1000 HAS.

13 L. LOJARITHNIC 359-1256

STRESS: OP LIFE @ 1.0W, 30V DESCRIPTION: 11C403 ED-X, SX-0, SP-O, PG-A SAMPLE SIZE: 100 (35, 25, 25, 25) LOTNO 304315

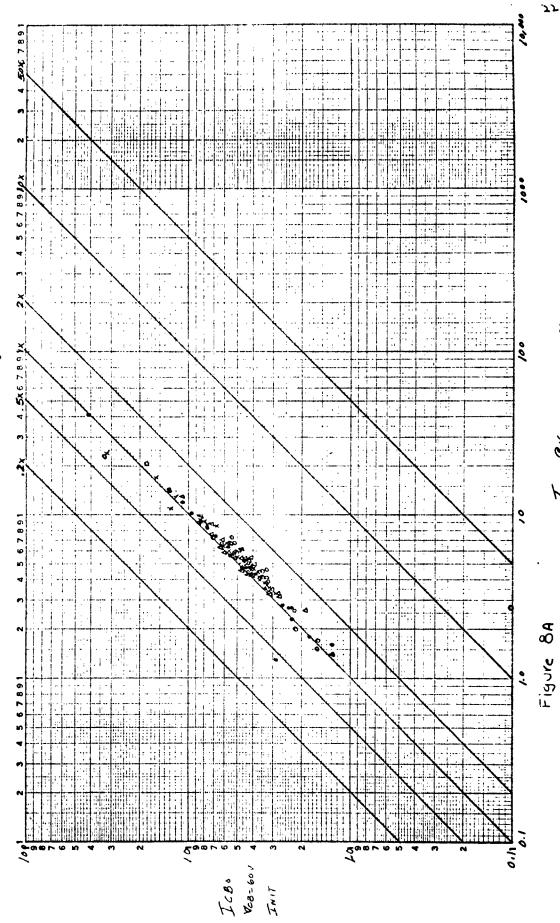


ICBO OVER-60V, 1000 HAS.



Man REUR, 106 A. C. M. C

STAESS; OP.LIFE @. SW, 20V LESCRIPTION: 1/C403 ED-X; SX-O; SP-O; P6-A SAMPLE SIZE: 100 (19,25,15,15) LOTNO: 304317



Figure

16.117.77100 Inch Districts

23

1000HRS. ICBO VCB= 601 Figure 9 -00 VCB=60V

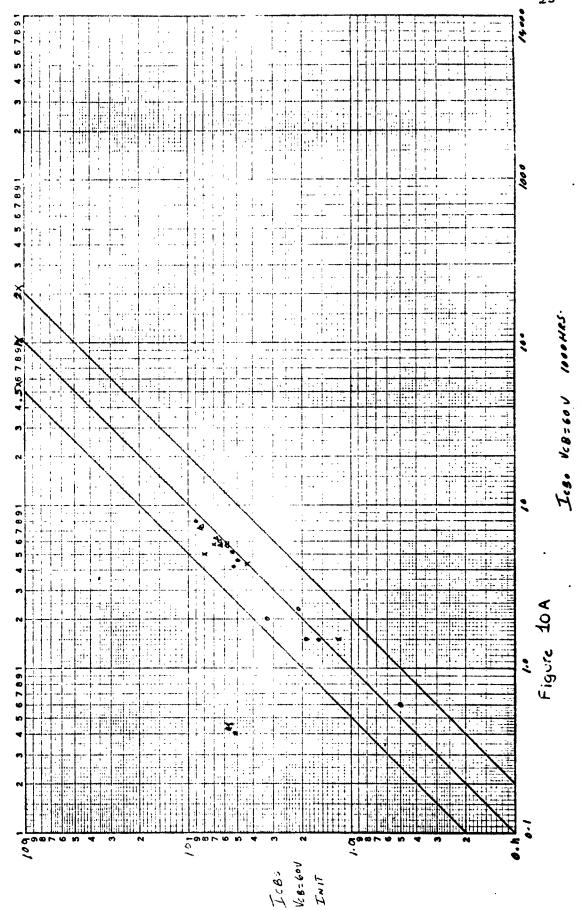
#\_{RELIEVED TEMP++45V STEPSTEESS

SAMPLE SIZE: 50 (14.11, 13, 14) LOTAR 305205 STRESS: OP.LIFE @ 1.6 W , 30V

NTHMIC 359-125G

LOGARITHMIC 359-125G

STRESS: OF LIFE CLOW, 301 FAST CYCLE 3AMON, 3MIN-OFF DESCRIPTION: 27912N2194, 6D-X, 3X-o, Sp-o, P6-b SAMPLE SIZE: 25(7, b, b, b) LOTNO. 312302



the non-cycled devices, there was no significant difference in failure rates between the two tests. Therefore, since the IC combination used in the collector of the life test circuits (to suppress oscillation) presents a potential transient hazard (a 15-V. spike on the collector was seen on turn-off of the cycled devices), it has been decided to run the Phase II devices at the steady state so that neither purposely nor continually will they be exposed to this legard.

#### [ Phase II Status and Data Analyses.

Electrical permeter at bility analyses for devices undergoing the Temperature with Back-Birs Voltage serving has been performed. The maits are been subjected to a total or 200 hours of much stress personing - namely, a balanced, homogeneous assignment of 480 devices each to 200°C, with 45 V, and to 280°C, with 45 V, as described in the third quarterly rejort under the Proposed Phase II Experiments (Filtr 5B). The devices are presently undergoing the stabilization bake, to be followed by centrifuge, prior to a extended multi-level life test. An abilitional homogeneous group of 4.00 devices will not receive any pre-life test stress screening, so that the effectiveness and efficiency of the temperature with voltage and contribute screening can be excluded on the life testing (See Figure II in this report).

Analyses besed on the effects of JOO downs of bender ture and wolt. We show devices from both streams to be producing ably well-for violation to the chart and graphs relicating to it. Discussion will report 1. Replication to the tistic I testing for childer the two abresses of \$\Delta T\_{OBO}\$ to U. (i.e., critimetic shift from initial) and percent of will arom initial for lyE, Vor(SAT) and VBE(SAT) were insulations.

Figure 14 answer the definition where the class A Iggo that. This is a distributionfree test and on the maintain levil than abween two undependent sample cumulative obepoint stiers (known at the Kolmogorov-Sairnov Sairnov Sair).

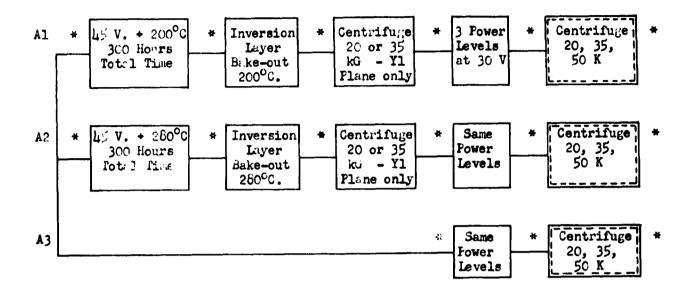
Figures 12 and 1° report the excellent fill of \( \Delta \) ICBO on the tril of the log-normal distribution for feeble, with voltage and for a \$100. With voltage respectively. The most show the points of shirt for the early (c/-haur) and the last (300-hour) replicates. Example of these curves are how extremely well-behaved these devices required ble degradation. The a louisted least square line equations for the 6/-hour and [ d-hour a d-cobs are shown. To mean and standard aviations are six of times from the squations. Use of these parameter estimates allows for the prediction of the proportion of devices lying outside any choice himle of ICBO degradation, i.e., \( \Delta \) ICBO, for the design ted hours on test.

Figures 15, to end 17 show the percentiles of percent a shift for hyp, VCE(SAT) and VBE(SAT) respectively for both some threases. The percentiles of shift for how devices per atress are given from the 1sb to the 59th percentile. It can be seen here, again, that raising the temperature from 200°C, to 280°C, has little effect on the stability of these parameters for the 300 hours of testing. However, at tistically significant results were obtained on the analysis based on BVCBO percentage shift. While devices from neither stress degraded (lowered BVCBO), the distribution of percentage shift of BVCBO for the higher stress (280°C, with voltage) was significantly more to the right on the percentage shift axis. Figure 19 contrasts the histogram of BVCBO percentage shift for both stresses for the early and the late read-outs. Above the histogram, the table and the results of the Kolmogorov-Smirnov two sample test is shown. The reasons for the tendency of

BVCBO to rise more sharply for the higher stress cannot as yet be explained. Figure 18 contrasts the percentiles of percentage shift between the two stresses.

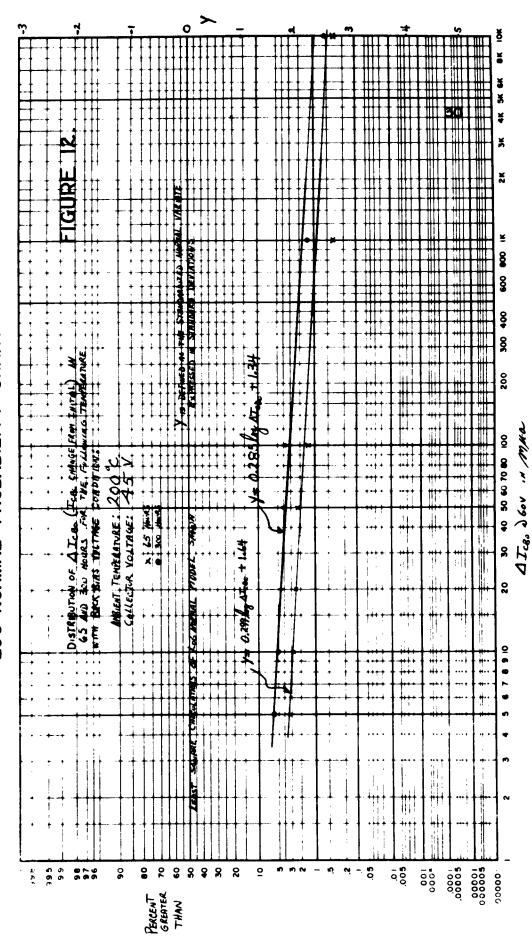
Analysis of the Phase II program will continue and will be reported later.

FIGURE 11 - PROPOSED PHASE II EXPERIMENTS.



- B \* femperature + 45 V. Step-Stress 200 Hours/Step only. Read as in Phase I
- C femper ture Alone Step-Stress 92 Hours/Step up to 360°C.
  Read as in Physic I
- D Contrifue Step-Stress
  As in Flase I
  - \* = Recd I<sub>CO, hrE, VCE(SAT), VBE(SAT), BVCEO.</sub>

LOG-NORMAL PROBABILITY CHART



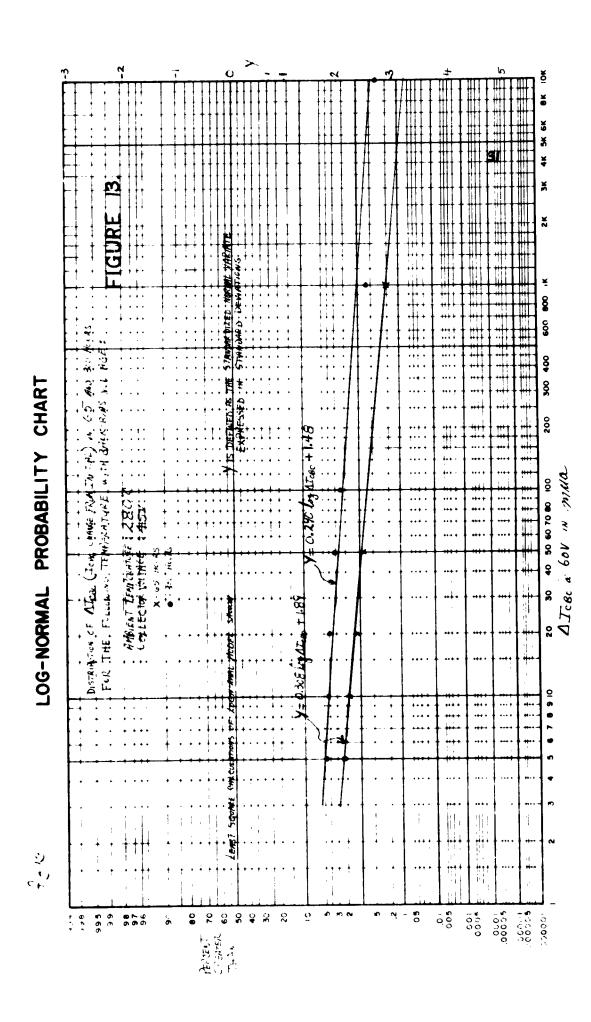


FIGURE 14

Table Showing the Cumulative Percentages and Results of the Statistical Testing  $^*$  for Significant Differences of Distribution of ICBO Shift from Initial ( $\Delta$  ICBO) for 200°C. Temperature plus 45 V. Back Bias Stress and 260°C. Temperature plus 45 V. Back Bias Stress of 300 Hours Duration. (Balanced, homogeneous sample of 480 units at each stress).

Shifts of ICBO in millimicroamps.	5	10	20	50	100	1,000	10,000	100,000
Fercent of Units Shifting that indicated amount or less for 200 C. + 45 V.	94.2	95.0	95•4	9 <b>5.</b> 6	96.0	98.75	99.38	99.8
Fercent of Units Shifting that indicated amount or less for 280°C. + 45 V.	95.2	95.8	96.0	96.7	97•5	99.38	99.6	99.8
Absolute Differences of Cumulative Forcentages	1.0	9•0	0•6	1.1	1.5	0.63	0.22	0.0

MAXIEUR DIFFERENCE -

\*\* 5% Critical Value = 9
10% Critical Value = 8

#### RESULT: STATISTICALLY INSIGNIFICANT.

- \* = The distribution free Kolmogorov-Smirnov test based on maximum deviation between two independent sample cumulative step functions.
- \*\* = Statistically significant at the 5% critical level is equivalent to stating that the probability of obtaining that maximum difference observed under the assumption of no distribution differences between the prent populations is less than a 1 in 20 chance.

FIGURE 15

Fercentiles of Percentage Shift for hyp at  $V_{CE} = 1 \text{ V.}$ ;  $I_{C} = 150 \text{ mA.}$  Shown for  $200^{\circ}$ C. with 45 V. and for  $280^{\circ}$ C. with 45 V. at Each Read-out Time.

			wit., 4:	V.
1 1		HO	OURS	
	65	130	200	300
1% 2% 5% 10% 25% 75% 75% 75% 75% 75% 75% 75% 75% 75% 7	76431 	7 0 5 4 2 1 0 1 2 3 4 + + + +	7654320122 ++22 ++3	76543201233

280°C. with 45 V.										
	HOURS									
65	130	200	300							
98642124568 ++++	886664202356	98764202342	18764202357							

FIGURE 16

Fercentiles of Fercente, e Shift for VCE(SAT) at 15 and 150 mA. Shown for 200°C, with 45 V. and for 260°C, with 45 V. at Each Read-out Time.

		200°3. 1	vita 45 '	٧.
	65	130	200	300
18 58 105 55 55 55 55 55 55 55 55 55 55 55 55 5	- 7 4 3 1 - 3 5 6 9 + 11	- 18 - 12 - 96 - 71 - 25 - 8 + 10	- 11 - 10 - 7 - 6 - 3 - 1 + 2 + 5 + 7 + 12 + 19	- 13 - 10 - 7 - 5 - 3 0 + 2 + 4 + 6 + 10 + 27

	280°C. with 45 V.									
HOURS										
(%)	130	200	300							
543202356127 +++++++	- 12 - 9 - 7 - 5 - 3 0 + 2 + 4 + 6 + 8 + 10	- 12 - 9 - 5 - 0 - 4 + + 5 + 8	- 13 - 8 - 5 - 4 - 1 + 3 + 8 + 11 + 11							

FIGURE 17

Fercentiles of Percentage Shift for  $V_{\rm HE}(SAT)$  at 15 and 150 mA. Shown for 200°C. with 45 V. and for 280°C. with 45 V. at Each Read-out Time.

		200°C. 1	with 45 V	<i>I</i>
	65	130	200	300
1% 2% 5% 10% 10% 50% 75% 75% 75% 95% 95%	- 6 4 0 0 1 1 2 2 2 2 2 2 4 + + + + + + + + + + + + +	-7 -1 -0 +1 +2 +2 +2 +2	-7 -3 -1 0 0 +1 +2 +2 +2 +3	9-100112223 +++++

	280°C. with 45 V.										
	НС	URS									
65	130	200	300								
-5 -10 +11 +12 +2 +2 +3 +3	-7 -0 0 +1 +2 +3 +1	-7 -1 0 0 +1 +2 +3 +3 +3	72001123344								

FIGURE 18

Percentiles of Fercentage Shift for BV<sub>CBO</sub> at 100 uA. Shown for 200°C. with 45 V. and for 280°C. with 45 V. at Each Read-out Time.

		200°0°, with 45 V. HOURS								
	<b>65</b>	130	200	300						
1% 2% 5% 10% 25% 75% 75% 95% 95% 95%	- 18 + 1 + 1 + 5 + 7 + 10 + 12 + 14 + 16 + 19	- 25 - 2 + 1 + 1 + 8 + 10 + 13 + 14 + 17 + 20	- 50 - 24 + 1 + 6 + 9 + 11 + 13 + 15 + 17 + 20	- 57 - 41 + 1 + 0 + 9 + 11 + 16 + 16 + 20						

	280°C. w	rith 45 1	ī <u>.</u>
	HC	URS	
65	130	200	300
+ 1 + 1 + 1 + 5 + 12 + 17 + 21	- 1 2 + 1 + 1 + 1 + 18 + 23	- 16 + 1 + 1 + 7 + 11 + 19 + 21	- 34 + 1 + 1 + 1 + 7 + 14 + 19 + 24
+ 24	<b>+</b> 26	+ 27	+ 27
+ 27½	+ 31	+ 32	+ 31
+ 31	+ 34	+ 34	+ 34

35

FIGURE 19 - BV<sub>CBO</sub> FERGENTAGE SHIFT FROM INITIAL READING

The trble shows the cum lative percent up to tue prouping indicated.

<b>8</b> 53 <b>+</b> <	T	·			1.	-	
>+ 5% >+15% >+2 <b>4+15% 4+</b> 25%	2.65 6.19	70.1 51.0	10 30	Maximum Difference	Value 13.6	SIGNIFICANT	
* \$	~) ~)	0.00 SS 0.00	1. 1.	S N			
57.7	H 1		5•0	65 HOURS	<b>1</b>		
<-25% * 5% * 15% <-15% <- 5%		U	ن• <u>آ</u> - ن	~ <del>—</del>	20001		

- E. Conclu- Pre-tests performed to date have indicated that: sions
  - 1. Six hundred hours of 200°C. to 280°C. produces no significant mechanical degradation of the device (degradation defined here as an open or short after 35 KG centrifuge). As a result of this pre-test, both 200°C, with voltage and 280°C, with voltage are being used as screening tests in Phase II.
  - 2. No significant difference in 35 KG mechanical strength exists between those devices which had previously been stressed at 20 KG and those which had not.
  - 3. No significant difference in failure rates was observed between the 0.8, 1.0, 1.2, 1.4 and 1.6 Watt stresses. This means that either there is no difference or, more probably, that the sample size used was not large enough to detect the existing difference. It is interesting to note that devices operating at the 1.6, 1.4 and, to some extent, at the 1.2 Watt levels are actually operating in thermal runaway. The base lead of such a device is open (because of the back-biased diode in the life test circuit base connection), and the device is "transisting" because of thermally-generated base carriers. Since each device appears to seek its own power level, it is necessary to take periodic on-rack measurements of power and voltage on each device.
  - 4. There was no significant difference in 1.6 Watt, 1,000-hour, failure rate between those devices which had successfully passed an extended voltage plus temperature screen and those devices which had not been subjected to the screen. This offers some preliminary indication that voltage and temperature may not be an effective screen for this type of device. Phase II, however, should provide a better indication of this.
  - 5. Since the cycled test offered no evidence of higher failure rates than the non-cycled test, and since there is somewhat of a voltage transient problem on the operating life racks, Thase II tests will be conducted in the steady state.
- F. Program Continuance of the program proposed in the third quarterly report.

  for next
  Quarter
- IX. AREA OF WORK INSPECTION AND QUALITY CONTROL FLAN.
- 1 A. Work Item Inspection and Quality Control Manual.
  - B. Abstract During this work period, Process Flow Diagrams were coded for cross-reference to internal document identification. Sections I and II of the Manual were completed. Three copies of the Manual were forwarded to the Electronics Materiel Agency for approval.

- C. Purpose The Inspection and Quality Control Manual outlines the total Quality Control plan to be implemented during the production run phase of this contract.
- F. Program Complete, and revise where necessary, all documentation required for for next the implementation of the Inspection and Quality Control plan.

  Quarter

## PROFESSIONAL PERSONNEL

## and

## TOTAL APPLIED EFFORT

## for period covering

1 February, 1963 - 30 April, 1963.

## Personnel

# Man-Hours

H. M. Calder

4,220 total

Dr. A. R. DiPietro

- J. L. Durso
- A. Fox
- F. K. Glasbrenner
- T. E. Jacobs
- R. T. Kobler
- R. H. Lanzl
- C. E. Logan
- A. Poe
- J. C. Richardson
- R. E. Smith
- J. F. Wholey

#### U. S. ARMY ELECTRONICS MATERIEL AGENCY.

## Production Engineering Measure

DA-36-039-SC-86727

## Silicon Grown Diffused Transistor

2N336

The purpose of the Production Engineering Measure Program is to improve the production techniques on the Silicon Grown Diffused Transistor type 2N336, with a maximum failure rate of 0.01% per 1,000 hours at a 90% confidence level at 25°C. as an objective.

Fourth Quarterly Report

31 January, 1963 30 April, 1963

General Electric Company Semiconductor Products Department Syracuse, New York.

Report Prepared by:

P. W. Olski.

Approved by:

1 R McLenghlin

## TABLE OF CONTENTS

		<u> </u>
1.	Abstract	1
2.	Purpose	2
3.	Narrative and Data	2
	3.1 Passivation	2
	3.2 High Temperature Main Sealing	3
	3.3 Experimentation and Evaluation	3
	3.3.1 Reliability Experiment	3
	3.4 Characteristic Distributions	15
4.	Conclusions	26
5.	Program for Next Quarter	27
ó <b>.</b>	Fublications and Reports	28
7.	Professional Personnel and Total Applied Effort	29

## 1. ABSTRACT

## Passivation.

This phase of the contract is complete. Evaluation results are reported below.

## High Temperature Main Sealing.

This phase of the contract is complete, with a production capacity of 1,200 units per hour attainable without automatic cap loading.

## Experimentation and Evaluation.

A statistically designed experiment, involving 400 units, to analyze the rotary cap welder is in progress. The experiment is based on the results of the encapsulation experiment and is aimed toward optimization of gas flow rate with respect to reliability.

The evaluation of the automatic passivation experiment reveals that there is no significant difference between the automatic system and the prototype. The automatic system is therefore recommended for installation in the production line. During the experiment, it was determined that a high temperature, back-bias voltage ( $200^{\circ}\text{C}$ .;  $15^{\circ}\text{V}$ . VCB) screen gives statistically significant results in permitting early detection of ICBO up-shifters on high power life tests. It was also determined that  $250^{\circ}\text{C}$ . and  $300^{\circ}\text{C}$ . storage produce failures in the bulk which degrade the breakdown voltage. Power failures are surface-connected.

#### Characteristic Distribution.

Weekly parameter distributions of fhfb, hrb, hob, NF, VCE, Cob, hfe (+25°C. and -55°C.), BVCBO, BVEBO, ICBO (+25°C. and +150°C.) are included for weeks 1 through 20 of 1963.

#### 2. PURPOSE

The purpose of the Production Engineering Measure Program is to improve the production techniques on the Silicon Grown Diffused Transistor type 2N336, with a maximum failure rate of 0.01% per 1,000 hours at a 90% confidence level at 25°C. as an objective.

In the fabrication of semiconductor devices there are inevitably critical process steps which, due to process variability, exert an influence on test yields and also on long range reliability. In order to achieve the reliability objective of this program, two key process steps have been singled out to maximize process control. By redesign of initial production equipment in these two areas, the latest processing techniques can be incorporated, while minimizing process variability, and at the same time greatly increasing production capability. The two specific work areas referred to above are Surface Passivation and High Temperature Main Sealing.

The objectives of this report are now noted.

#### 2.1 PASSIVATION

Installation of equipment which will:

- 1. Permit the incorporation of the latest processing techniques.
- 2. Minimize process variability.
- 3. Increase production capability.

#### 2.2 HIGH TEMPERATURE MAIN SEALING.

Installation of main seal welding equipment which will meet the process requirements, defined as necessary to achieve highly reliable device performance, and which will also provide for volume production.

#### 2.3 EXPERIMENTATION AND EVALUATION

#### 2.3.1 Reliability Experiment.

Determination of the reliability of the automatic passivation process versus the prototype method.

#### 2.4 CHARACTERISTIC DISTRIBUTIONS

The establishment of a system to monitor the electrical parameter distributions on the LJDLC line where the 2N336 is produced.

## 3. NARRATIVE AND DATA

## 3.1 PASSIVATION

The automatic passivation equipment was installed, as reported in the second quarterly report, and the evaluation of the equipment is reported below.

#### 3.2 HIGH TEMPERATURE MAIN SEALING

Analysis of the high temperature main sealing process is in progress.

A total of 400 devices, fabricated over a period of several weeks, has been encapsulated using both the new rotary cap welding design and the present standard encapsulation system. The high temperature and the duration of purging time are maintained for both systems at constant levels, as established from previous experimentation.

Three levels of gas flow rate will be used for the rotary welder to establish an optimum. All other materials, process steps and equipment preceding and following encapsulation have been kept identical. The units have been identified so that the period of production as well as the encapsulation system (and the different flow rates for the rotary system) can be established.

All units will be processed through a temperature and back-bias voltage screen and put on an extended accelerated power life test

Results from this experiment will be reported in due course.

Since the production rate of 1,200 units per hour, as presented in the proposal, is attainable without automatic cap loading, this phase of the process has been dropped.

## 3 3 EXPERIMENTATION AND EVALUATION

the following pages contain the report on:

## 3.3.1 RELIABILITY EXPERIMENT

## OBJECTIVE.

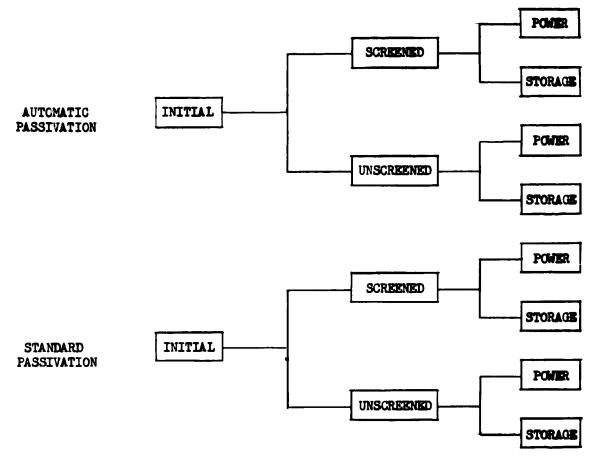
The primary purpose of the Passivation Experiment is to allow a valid comparison to be made between the new automated surface passivation system (as described in previous reports) and a prototype of the proposed system (referred to as the standard passivation system). The comparison will be based on the reliability and distribution performance on accelerated power and temperature storage conditions for devices processed through both passivation systems.

A secondary purpose is the demonstration of the effectiveness of a short time (100 hours) of 100% stress screening of temperature (200°C.) with back-bias collector voltage (45 V.) in culling out potential n-inversion failures on long-term high power tests.

#### EXPERIMENT DESIGN.

A total of 500 devices, fabricated over a period of several weeks, is used in this experiment. All material, process steps and equipment used in fabrication are identical, except for the passivation processes. The passivation procedure, using both systems, has been performed at several production periods to assure adequate replication of the experimental design.

Figure 1 shows how the devices are allocated throughout the experiment in a balanced fashion. Thus, the design reduces to a replicated 2<sup>3</sup> full factorial, viz. 3 variables, each at two levels, as shown in the figure.



## SCREENING CONDITIONS.

## LIFE TEST CONDITIONS.

200°C.; 45 V. V<sub>CB</sub> for 100 Hours.

## POWER:

Stabilization Bake 50 Hours.

760 mw.; 30 V.  $V_{\rm CB}$ ; 25°C. ambient temperature Emitter current cycled 50 minutes ON, 10 minutes OFF.

## STORAGE:

250°C. ambient temperature.

Minimum 1,000 Hours.

FIGURE 1 - EXPERIMENTAL DESIGN.

## TEST CONDITIONS AND MEASUREMENTS.

All devices are measured initially and parameter screened before being considered as experimental potential, i.e.,  $I_{CBO}$  at 30 V.  $V_{CB} < 50$  mmA, and  $I_{CEO}$  at 25 V. < 100 mmA. This is followed by a 100-hour stress screen of temperature (200°C.) with back-bias collector voltage (45 V.) applied to a random balanced half of the total devices. The stress-screened units are parameter screened and subjected to a 50-hour stabilization bake, then parameter screened again.

Both stress-screened and non-stress-screened devices are then divided, again in a random balanced manner, between a 1,000-hour accelerated power test (760 mm.; 30 V. VCB; 25°C. ambient temperature with emitter current cycled 50 minutes ON, 10 minutes OFF) and an accelerated temperature storage test (250°C.).

(The life testing of automatic passivation units is to be extended to provide further information, depending on socket availability).

#### CONCLUSIONS AND RECOMMENDATIONS.

Statistical analyses (both on an attribute and on a variables basis) comparing the two passivation systems showed no statistical significance, either during stress screening or during extended accelerated power and temperature storage tests.

Tables 1, 2 and 3 show the percentiles of  $I_{CBO}$  leakage,  $h_{F\!R}$  percent shift from initial reading and BVCBO degradation respectively for different combinations of passivation system, stress screening and accelerated life test. In the case of stress-screened units, "initial" reading is the reading after the stabilization bake, immediately prior to life test. The data is shown for each successive readout time on the accelerated life tests.

Table 4 and Tables 5, 6 and 7 show the Contingency Tables and summarized Chi-square test results. These demonstrate statistically significant differences (at the 0.05 level) between stress-screened and non-stress-screened product and the different life tests both on an attribute (Table 4) and on a variables (Tables 5, 6 and 7) basis, while non-statistically significant results are obtained between the two passivation systems.

Figure 2 demonstrates the very positive correlation between ICBO "up-shifters" on short-term (100 hours) temperature plus back-bias voltage screening and long-term (1,000 hours or more) accelerated power testing. This correlation is not evident between temperature and back-bias screen and accelerated temperature storage life test, as can be seen in Figure 3.

Reject analysis reveals that the failures on  $250^{\circ}$ C. storage life test show an extreme breakdown voltage degradation which is very much time-dependent as well as temperature-dependent, and independent of temperature and back-bias voltage screening. Weibull plots of failure-in-time give a slope ( $\beta$ ) of 1, showing a constant failure rate. For  $250^{\circ}$ C., this degradation occurs in the neighborhood of 1,000 hours; raising the temperature to  $300^{\circ}$ C., for example, will more than halve the time at which degradation occurs. These failures are not recoverable on re-etching and appear to exhibit a non-surface phenomenon.

The few failures occurring on the 760 mw. life test (in the neighborhood of 1%) are recoverable on re-etching, however, and appear to be of the surface contamination type.

## RECOMMENDATION.

Based on the results of this experiment, the new automatic passivation system is recommended for installation in the production line.

TABLE 1

10, 50 and 90 Percentiles of  $I_{CBO}$  at  $V_{CB}$  = 30 V. at Initial (Value after Bake for screened units) and after 20, 160, 500 and 1,000 Hours of Accelerated Life Testing.

		(*	760 m	w.; 2	5°C.	ambient	ED POWE temper 50 min	atur				
			SCRE	ENED				UNSC	REENED	)		
		Ш	æ re	ST HO	urs		LIFE TEST HOURS					
		Init	20	160	500	1000	Init	20	160	500	1000	
	10%	0	0	0	0	1	0	0	0	0	1	muA.
Automatic Passivation	50%	2	2	3	3	5	2	3	5	7	10	muA.
System	90%	9	9	10	15	23	19	15	29	90	134	mıA.
0.1	10,6	0	0	0	0	1	0	0	0	1	2	miA.
Standard Passivation	50%	2	3	2	3	5	2	3	3	6	8	ma.A.
System	90%	13	17	1?	17	34	15	13	30	42	58	mıA.

				AC	CELER		MPERATU	re si	TORACE	<del>,</del>		
			SCREENED					unscreened				
		III	LIFE TEST HOURS					Life	TEST	HOURS		
		Init	<b>2</b> 0	16C	500	1000	Init	20	160	500	1000	
	10%	0	0	0	0	1	0	0	0	0	1	muA.
Automatic Passivation	50%	2	3	2	2	2	2	2	1	2	3	muA.
System	90%	10	13	8	8	15	15	13	9	21	10	uA.
	10%	0	1	0	0	1	0	1	0	0	1	muA.
Standard Fassivation	50%	2	3	2	2	2	3	3	3	4	3	muA.
System	90%	18	29	12	10	12	12	32	18	18	46	muA.

TABLE 2

10, 50 and 90 Percentiles of  $h_{FE}$  % Shift from Initial (Value after Bake for screened units) at  $V_{CE}$  = 5. V.;  $I_{C}$  = 1.0 mA. at 20, 160, 500 and 1,000 Hours of Accelerated Life Testing

		(	ACCELERATED POWER  (760 mw.; 25°C. ambient temperature; cycled emitter  current 50 min. ON, 10 min. OFF).									
		<del></del>	s	C.KEEN	<b>E</b> D			UNSC	REENE	D		
		-	LIFE	TEST	HOURS		L	IF <b>E</b> T	<b>ES</b> T H	OURS		
		20	150	500	1000		20	160	500	1000		
	10%	3	ó	9	F		2	-24	5	-7†		
Automatic Fassivation	50%	12	16	23	17		10	15	25	18		
System	90%	19	28	36	25		20	33	46	35		
	10%	O	O	O	-14		2	7	8	1		
_	50%	13	15	19	14		74	19	24	16		
System	Y0%	21	21,	33	20		26	34	41	31		

			ACCELERATED TEMPERATURE STORAGE (250°C.)									
			s	CREEN	<b>E</b> D	UNSCREENED						
			LIFE	TEST	HOURS		L	if <b>e</b> t	<b>es</b> t h	OURS		
		20	160	500	1000		20	160	500	1000		
	10%	<b>-</b> 2	24	30	<b>-</b> 36		<b>†</b>	25	-33	-43		
Automatic Passivation	50%	5	. 2	-4	-10		3	-3	-5	-12		
System	90%	13	18	22	5/1		13	18	38	46		
24	10%	<b>2</b>	·-23	- 33	39		<del>-</del> 2	-27	-31	-36		
Standard Passivation	50%	5	2	6	12		5	-4	<b>-</b> 5	-11		
System	90%	11	12	20	17		24	15	23	22		

TABLE 3
and 90 Percentiles of BV<sub>CBO</sub> at I<sub>C</sub> = 50 uA. at Initial (Value after Bake for

10, 50 and 90 Percentiles	of BV <sub>CBO</sub>	at Ic -	50 uA. at Initial (Value after Bake for
screened units) and After	20. 160;	500 and	1,000 Hours of Accelerated Life Testing.

		(	760 m	w., 2	5 <sup>0</sup> 3 .	ambient	TED POWER  temperature, cycled emitter  50 min. ON, 10 min. OFF).						
		_	SCREENED					UNSCREENED					
			LIFE	TEST	HOURS		I	ife t	est f	our <b>s</b>			
		Init	20	160	500	1000	Init	20	160	500	1000		
Automatic	10.8	<b>U.</b> L	87	83	53	54	76	75	77	79	77	ν.	
Passivation System	50.6	133	132	<b>ى</b> رد	132	136	114	115	118	118	122	٧.	
System -	90%	162	101	166	161	161	152	152	193	159	159	٧.	
Standard	10%	70	71	6°	67	67	66	66	76	77	78	v.	
Passivation	122	<b>∡</b> 25	125	127	120	118	120	123	124	123	v.		
System	70 <b>%</b>	169	169	170	109	169	162	162	162	162	162	v.	

				ACCE	LERAT	ED TEAN	ERATURE STORAGE						
			SCREENED					UNSCREENED					
			Life	TEST	HOURS		I	ife t	est h	OURS			
		Init	20	100	500	1000	Init	20	160	500	1000		
A. A	10%	93	94	90	67	7.4	80	82	78	51	27	V.	
Automatic Passivation	50%	124	127	iżų	118	120	:11	129	118	110	102	٧.	
<b>S</b> ystem	90%	178	<b>1</b> 78	179	175	150	101	102	160	158	155	۷,	
g	10,3	76	8:	85	79	59	80	83	82	77	39	v.	
Standard Fassivation	50%	128	128	130	125	£09	122	126	127	116	111	٧.	
System	90%	163	164	<b>∡</b> 63	160	159	165	165	164	164	154	٧.	

TABLE 4

Two by Two Contingency Tables on Failures\* Showing Chi-Square Test Results Comparing Separately:

- A. Automatic versus Standard Passivation.
- B. Stress-Screen versus Non Stress-Screen.
- C. Accelerated Power Life Test versus Accelerated Temperature Storage Life Test.

Α.	AUTOHATIC	STANDARD	MARGINAL
	FASSIVATION	PASSIVATION	TOTALS
No. of Non-Falled Devices	182	205	387
No. of Falled Devices	±0	6	16
Marginal Totals	. 7	211	403
Calculated Uni Square 0.	9. STATIS	STICALLY INSIG	NIFICANT

B.	STRESS	NON-STRESS	MARGINAL
	Screened	SCREENED	TOTALS
No. of Non-Farled Devices No. of Farled Devices	207	180	387
	L	12	16
Marginal Totals	211	192	403

Calculated Chi-Squire = 4.92

5% Critical Chi Square (1 degree of Freedom) = 3.84 STATISTICALLY SIGNIFICANT AT THE 0.05 LEVEL.

C.	FOWER	STORAGE	MARGINAL TOTALS
No. of Non-Failed Devices No. of Failed Devices	493 3	494 43	387 16
Marginal Totels	196	207	403
Calculated Chi Square 4. 5% Critical Chi Square (1. STATISTICALLY STONIFICANT	de ree of Fre		1

\* : Failures are defined as those devices which exceed I uA. for ICBO at VCB = 30 V. on Life Test.

All devices have passed the multi parameter (ICBO and ICEO) streening criteria.

"Statistically significant at the 0.05 level" is equivalent to stating that the probability of observing a break-up between failures and non-failures under the assumption of no difference between the two types of devices is less than a 1 in 20 chance.

TABLE 5

Contingency Tables, Showing Chi Square Test Results Comparing the 30-V. VCB ICBO Distribution Separately for:

- A. Stress-Screened versus Non Stress-Screened.
- B. Accelerated Fower Info Test versus Accelerated Temperature Storage Life Test.

After 1,000 Hours on Life Test.

A.	SIRESS S	CREENED	NON · ST.ÆS	MARGINAL TOTALS	
Frequency Class mak.	Observed	Expected	Observed	Expected	
> 0	47,000	159 3 20 9 34.0 6.4	112 17 38 14 11	126.7 19.1 31.4 7.6	266 40 66 16 15
Margin 1 Totals	- 4.1		192		403

Calculated Chi-Square = 19%b 1% Criticul Chi-Square (4 de mass of Freedom) = 13%3 HIGHLY SIGNIFICANT.

₿.	ŀOW	EH:	SIO.	NA GINAL TOTALS	
Frequency Class mak.	Observed	Expected	Observed.	Expected	
> 0 \le 5 > 5 \le 10 > 10 \le 50 > 40 \le 1000 > 1000	103 19 50 11	129.4 19.4 32.1 7.8 7.3	10) 11 10 5	136.6 20 6 33.9 8.2 7.7	206 40 66 16
Marginal Totals	196		207		403

Calculated Chi-Square = 45.7

1% Critical Ch. Square (4 degrees of Freedom) - 13.3

HIGHLY SIGNIFICANT,

All devices have passed the multi purameter (ICBO and ICEO) screening criteria.

"Highly significant at the 1% level" is equivalent to stating that the probability of observing a break-up between frequency classes under the assumption of no difference between the two types of devices is less than a 1 in 100 chance.

TABLE 6

Contingency Tables, Showing Chi-Square Test Results Comparing the her Percent Shift from Initial Life Test Value at  $V_{CE}$  = 5 V.;  $I_{C}$  = 1.0 mA. Distribution Separately for:

- A. Stress-Screened versus Non-Stress-Screened.
- B. Accelerated Power Life Test versus Accelerated Temperature Storage Life Test.

After 1.000 Hours on Life Test.

Α.	STRESS-S	CREENED	NON-STRES	S-SCREENED	MARGINAL TOTALS
Frequency Class	Observed	Expected	Observed	Expected	
> 40 30	7 10 20 25 28 33 47 28 5	2.6 19.3 22.5 26.7 35.0 44.5 24.1 8.9	5 14 17 18 23 34 38 18 12	5.7 11.4 17.7 20.5 24.3 32.0 40.5 21.9 8.1	12 24 37 43 51 67 85 46 17
Marginal Totals	211		192		403

Calculated Chi-Square = 9.2 10% Critical Chi-Square (9 degrees of Freedom) = 14.7 STATISFICALLY INSIGNIFICANT.

В.	POW	ER	STOR	MARGINAL TOTALS	
Frequency	Observed	Expected	Observed	Expected	
Class					
> 4	_	٠, ٥			I
-40	0	5.8	12	6.2	12
3040	0	11.7	24	12.3	24
<b>-</b> 20 <b>-3</b> 0	1	18.0	36	19.0	37
-10 -20	b	20.9	37	22.1	43
010	12	24.8	39	26.2	51
0 +10	39	32.6	28	34.4	67
+10 +20	79	41.3	6	43.7	43 51 67 85
+20 +30	38	22.4	8	23.6	46
+30 +40	12	8.3	5	8.7	17
+40	9	10.2	12	10.8	21_
Marginal Totals	196		207		403

Calculated Chi-Square = 193.0
1% Critical Chi-Square (9 degrees of Freedom) = 21.7
HIGHLY SIGNIFICANT.

TABLE 7

Contingency Tables, Showing Chi-Square Test Results Comparing the BV<sub>CBO</sub> (I<sub>C</sub> = 50 uA.) Distribution Separately for:

- A. Stress-Screened versus Non-Stress-Screened.
- B. Accelerated Fower Life Test versus Accelerated Temperature Storage Life Test.

After 1,000 Hours on Life Test.

Frequency Class		STRESS-S	CREENED	NON-STRES	MARGINAL	
		Ob <b>served</b>	Expected	Observed	Expected	TOTALS
80 1 120 1 160 3 200	<b>€</b> 80 20 60 60	5 22 72 92 16 4	9.4 25.1 72.8 85.9 15.7 2.1	13 26 67 72 14 0	8.6 22.9 66.2 78.1 14.3	18 48 139 164 30
Marginal	. Totals	211		192		403

Calcal ted Chi-Square = 9.8

10.6 Critical Chi-Square (5 degrees of Freedom) = 9.24

5.6 Critical Chi-Square (5 degrees of Freedom) = 11.1

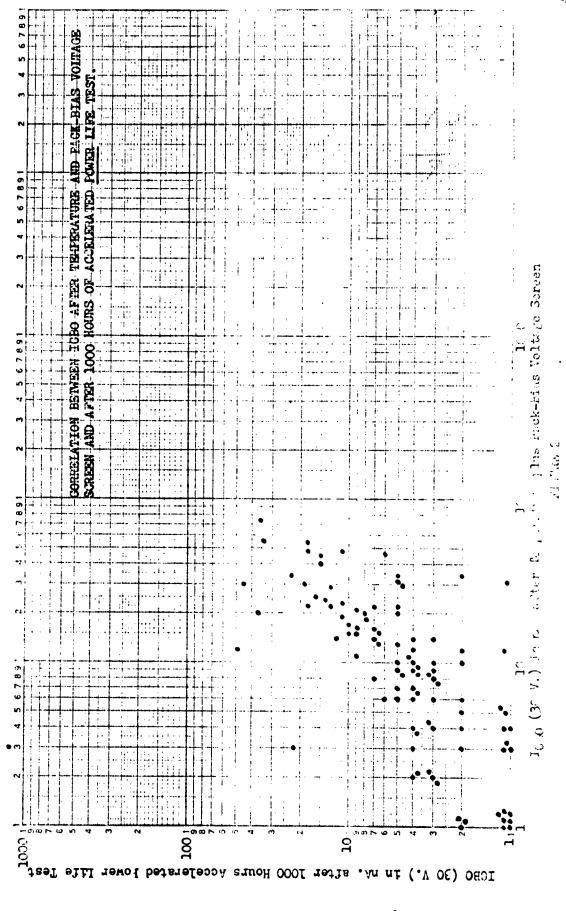
STATISTICALLY SIGNIFICANT AT THE 10% LEVEL.

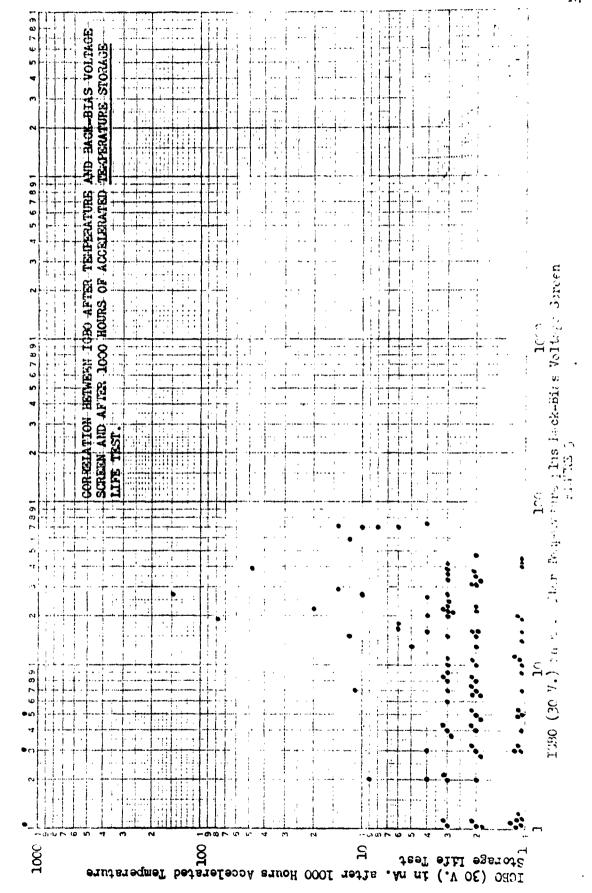
В.,	FOW	NER.	STOR	HARGINAL	
Frequency Class V,	Observed	Expected	Observed (	Expected	TOTALS
7	1 20 60 96 17 2	8.8 23.3 67.0 79.8 14.6 1.9	17 28 79 66 13 2	9.2 24.7 71.4 84.2 15.4 2.1	18 48 139 164 30
Marginal Totals	196		207		403

Calculated Chi-Square = 23.2

1% Critical Chi-Square (5 degrees of Freedom) = 15.1

HIGHLY SIGNIFICANT.





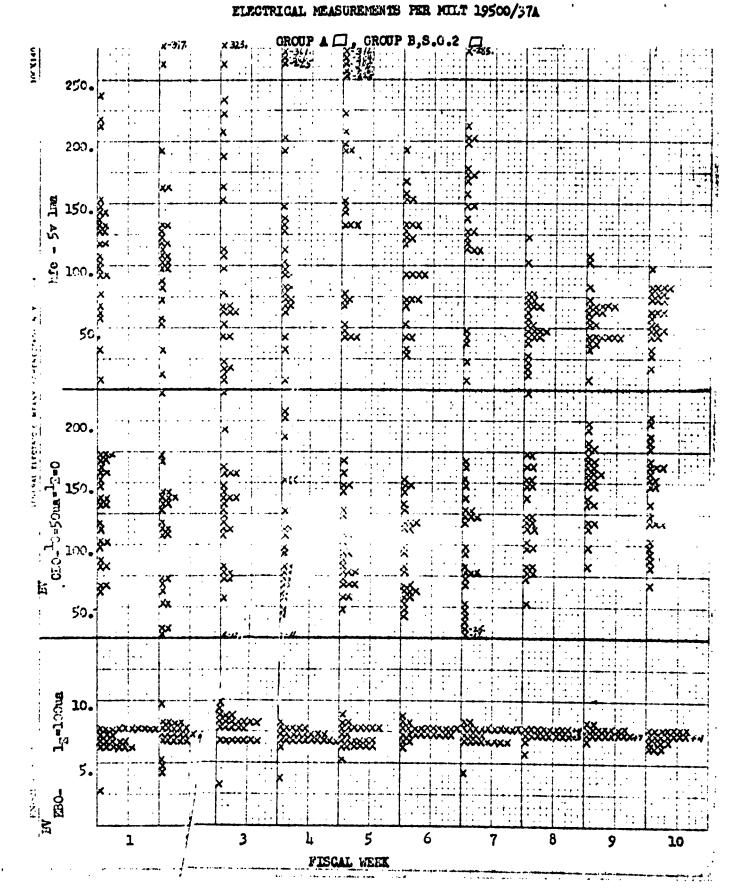
## 3.4 CHARACTERISTIC DISTRIBUTIONS

The attached report gives the weekly parameter distributions of BVEBO, BVCBO, hfe, ICBO at  $25^{\circ}$ C. and  $150^{\circ}$ C., and hfe at  $-55^{\circ}$ C. As stated in the last report, current gain hfe has been recorded rather than hfb, and BVEBO at IE = 100 microamperes has been recorded rather than IEBO at VEB = 1 Volt.

The Quality Control Report describing the quality practices exercised by the General Electric Company in the construction of 2N336 transistors for the U.S. Army Electronics Materiel Agency was sent to the Agency on 2-19-1963. A request for additional forms was filled on 4-12-1963. The manual will be used when the production run is begun.

## PARAMETER DISTRIBUTION BY WEEK

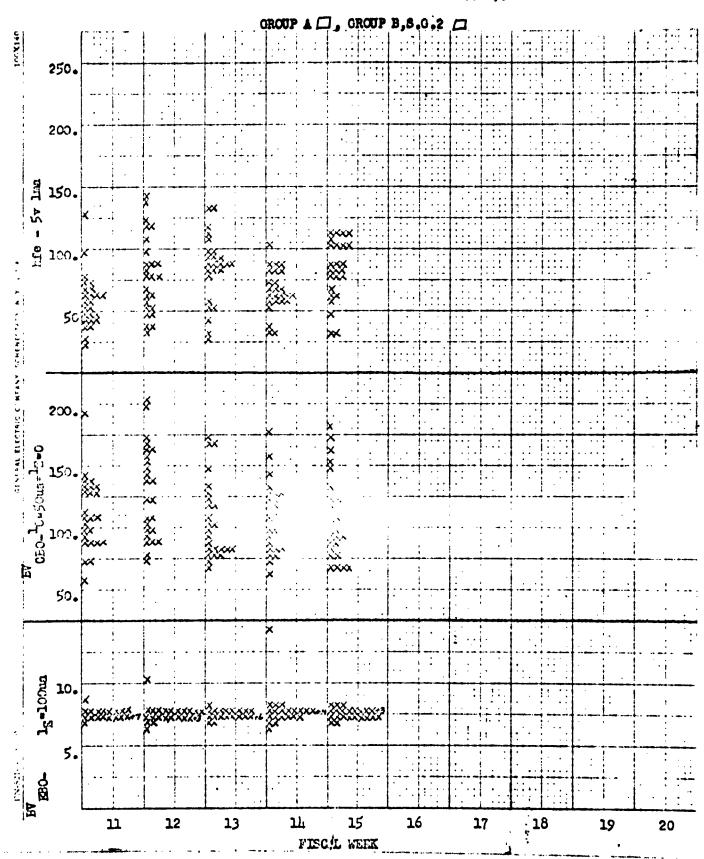
# 1963 - LUDLO LINE, (21332,21333,21335,21336)

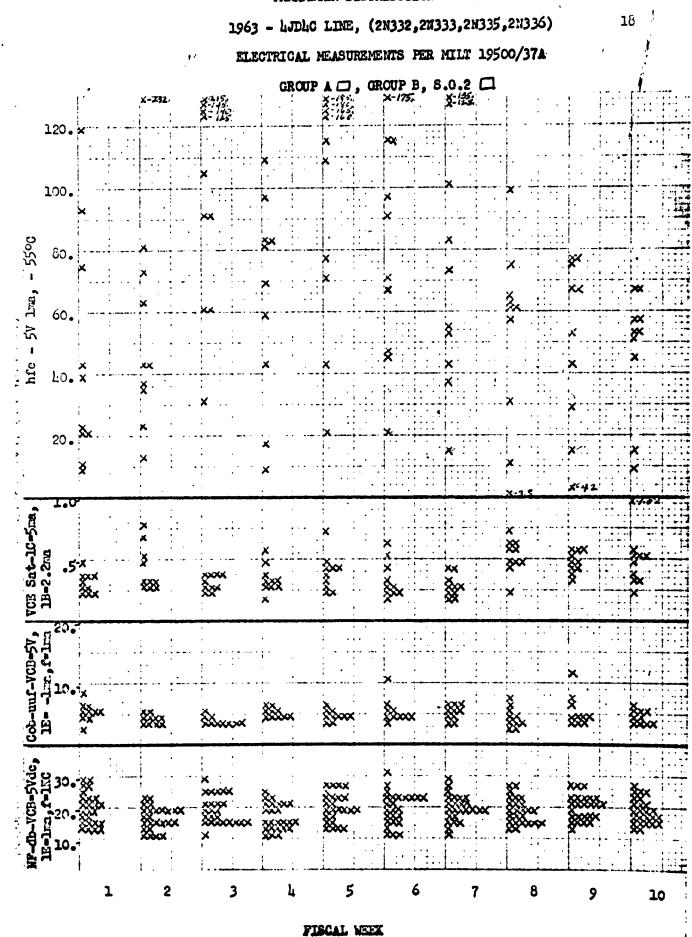


## PARAMETER DISTRIBUTION BY WEEK

# 1963 - LUDLIC LINE, (2N3)2,2N333,2N335,2N336)

# ELECTRICAL MEASUREMENTS PER MILT 19500/37A

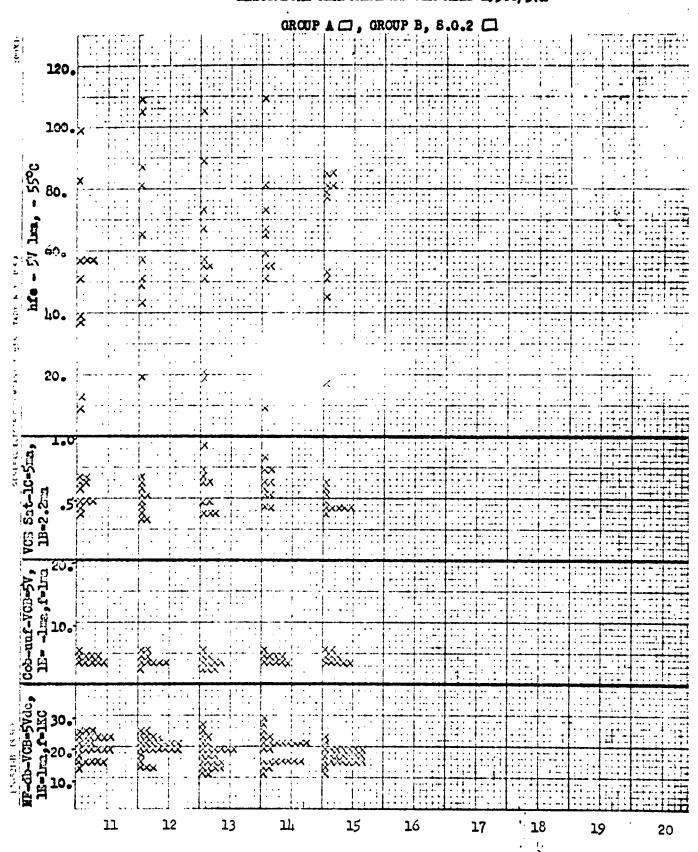




## PARAMET... DISTRIBUTION DY WEEK

# 1963 - hJDhC LINE, (2N332,2N333,2N335,2N336)

# ELECTRICAL MEASUREMENTS PER MILT 19500/37A



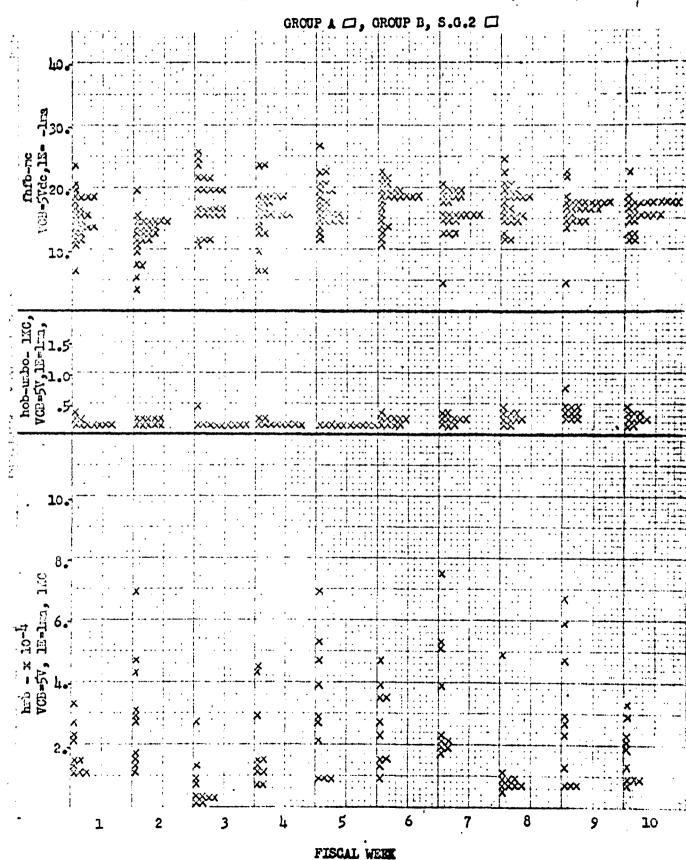
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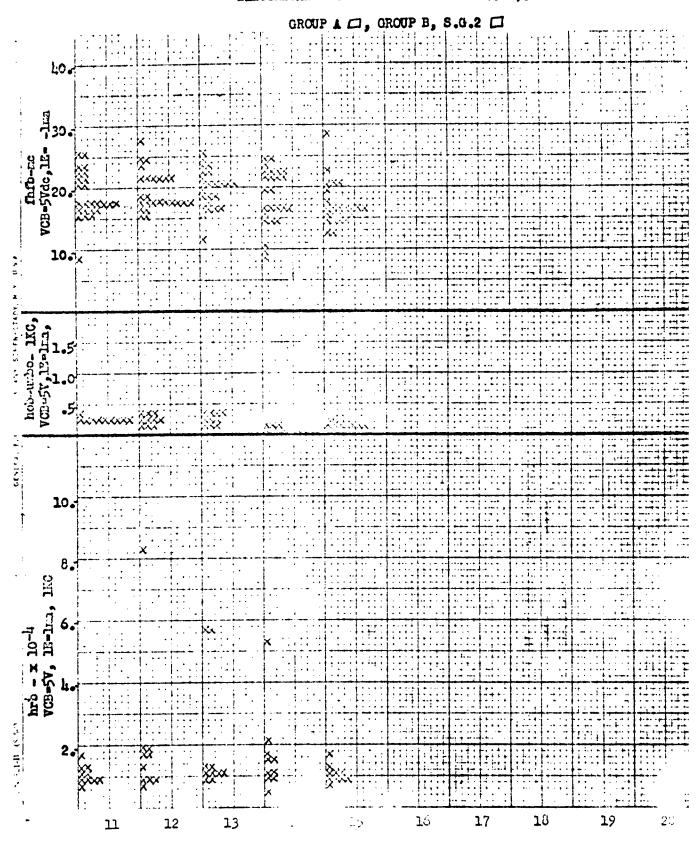
1963 - LIDLC LINE, (2N332,2N333,2N335,2N336)

ELECTRICAL MEASUREMENTS PER MILT 19500/37A



# 1963 - LUDLO LINE, (2N332,2N333,2N335,2N336)

# ELECTRICAL MEASUREMENTS PAR MILT 19500/37A



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1963 - 1,527,9 LTD, (2,532,51333,4355,8335)

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1963 - huho une, (20132,20333,2035,20336) KLECTRUCAL PEASUREMENTS PER HULL 19500/57A GEOUP B, S.D.2 . + 4 } 77 7 Ħ 8 ຊ 79 K 2 28 17

PARAMETER DISTRIBUTION BY MAKE

1963 - Ladic Ling, (20332,20333,2035,20336) ELECTRICAL NAASURETENTS FER MIST 19500/37A PARAMETER DISTRIBUTION DI WEST , GROUP B, S.O.2

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## 4. CONCLUSIONS

The passivation experiment has shown that the automatic equipment is not significantly different from the prototype, and its installation in the production line is fully justified. The reliability study performed during this experiment has shown a significant statistical difference between those units which have been subjected to a temperature and back-bias voltage screen and those which have not. This screen has the ability to remove the potential  $I_{CBO}$  up-shifters on both power and operating life tests. The failure mechanism appears to be surface-oriented. High temperature stresses of  $250^{\circ}$ C. and  $300^{\circ}$ C. appear to produce bulk failure mechanisms which are irreversible.

A main seal welding experiment is in progress to optimize the flush time and to check the reliability of the equipment. The automatic cap-loader has been abandoned, since the proposed production rates are attainable without it.

## 5. PROGRAM FOR NEXT QUARTER

## 5.1 PASSIVATION

This part of the program is complete.

## 5.2 HIGH TEMPERATURE MAIN SEALING

This part of the program is complete.

## 5.3 PRODUCTION RUN

This part of the program is ready and can be started as soon as authorization is given by the Agency.

## 5.4 EXPERIMENTATION AND EVALUATION

Evaluation of the rotary cap welder will be continued.

Evaluation of the production run will begin as soon as this part of the program is authorized.

## 5.5 CHARACTERISTIC DISTRIBUTIONS

The monitoring of the electrical parameter distribution of the 4JD4C line will continue. Parameters will be added as necessary or dropped, if it is found that they can be controlled via correlation with other parameters

# 6. PUBLICATIONS AND REPORTS

6.1 Formal Quarterly Report.

The Third Quarterly Report was completed, approved, and distributed.

1,096

# PROFESSIONAL PERSONNEL

and

# TOTAL APPLIED EFFORT

for period covering

31 January 1963 - 30 April 1963

MAN-HOURS PERSONNEL

F. J. Potter

P. W. Olski

D. F. Smith

T. E. Gates

C. L. Jeffers

F. Marapodi
W. A. Scherff
A. Fox